NSN 5961-01-317-1938

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-1938 **Inclosure Material:** Plastic **Overall Length:** 0.260 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.120 inches **Function For Which Designed:** Rectifier **End Application:** 4920-01-125-2115 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage and 40.0 working peak reverse voltage and 40.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli